



修订记录



描述

Silicon PNP transistor in a SOT-23 Plastic Package.

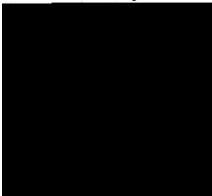
特征

$V_{CE(sat)}$
High current gain, Low collector-emitter saturation voltage.

用途

General power amplifier application.

内部等效电路



引脚排列



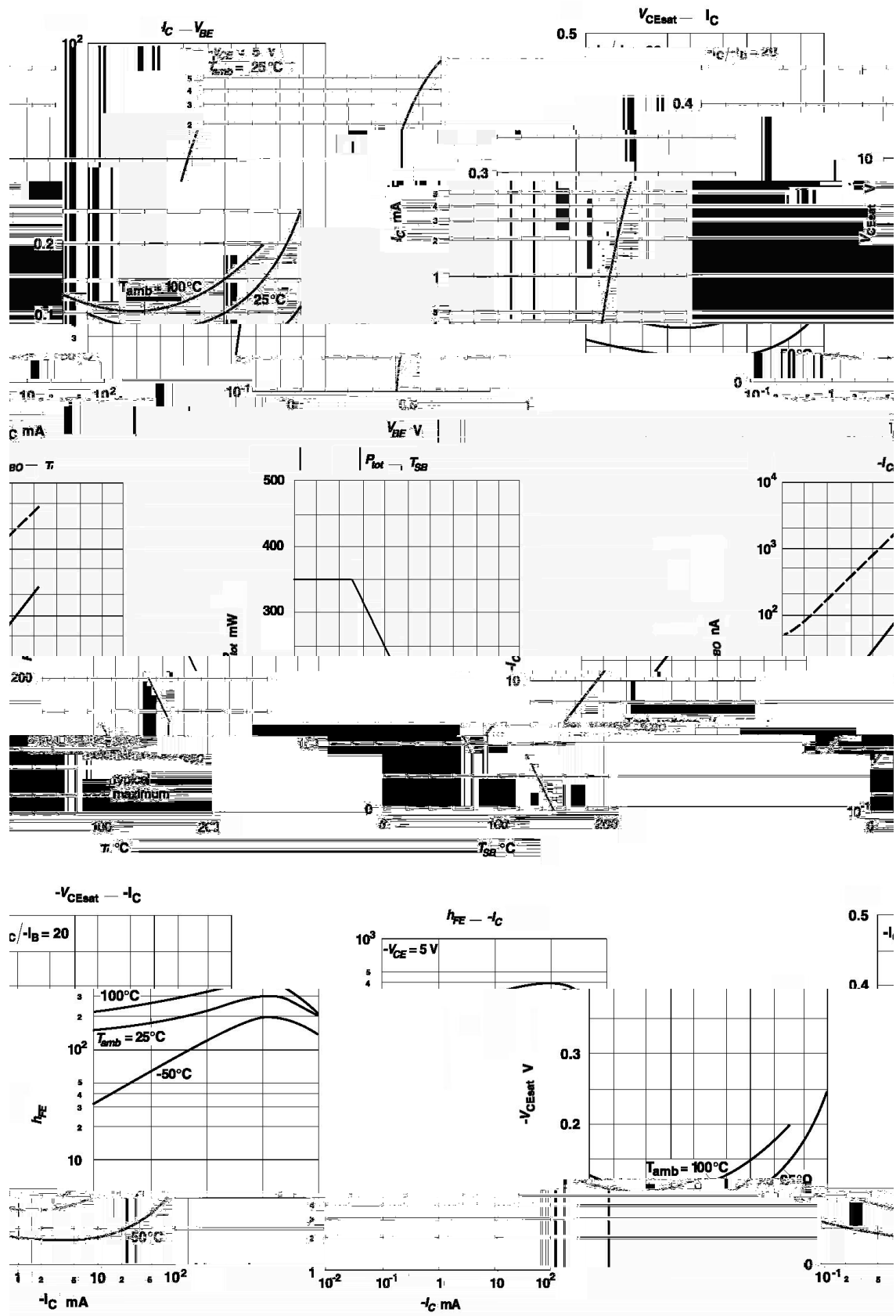
PIN1 Base PIN 2 Emitter PIN 3 Collector

放大及印章代码

h_{FE} Classifications Symbol	A	B	C
h_{FE} Range	125~250	220~475	420~800
Marking	H3J	H3K	H3L



电参数曲线图

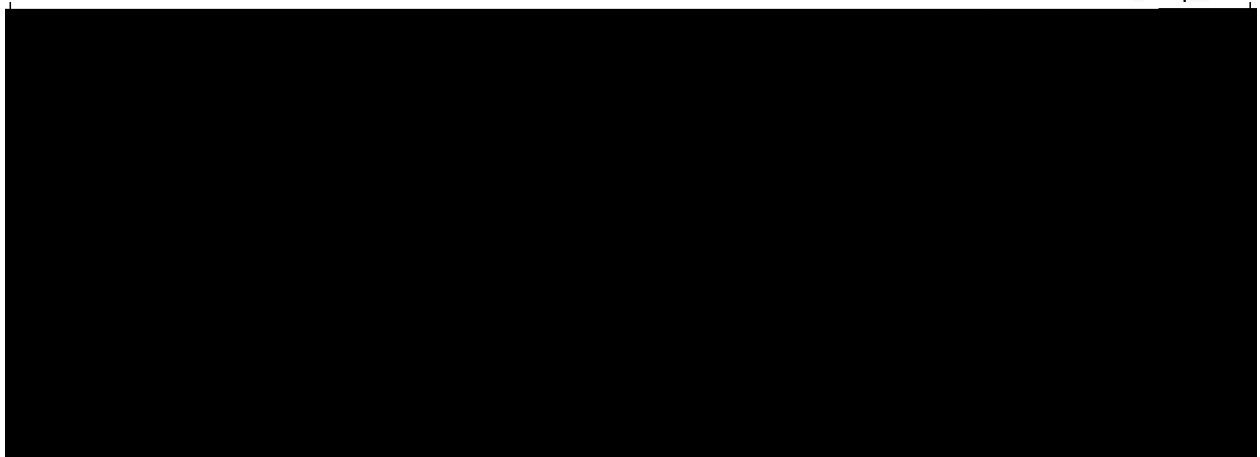
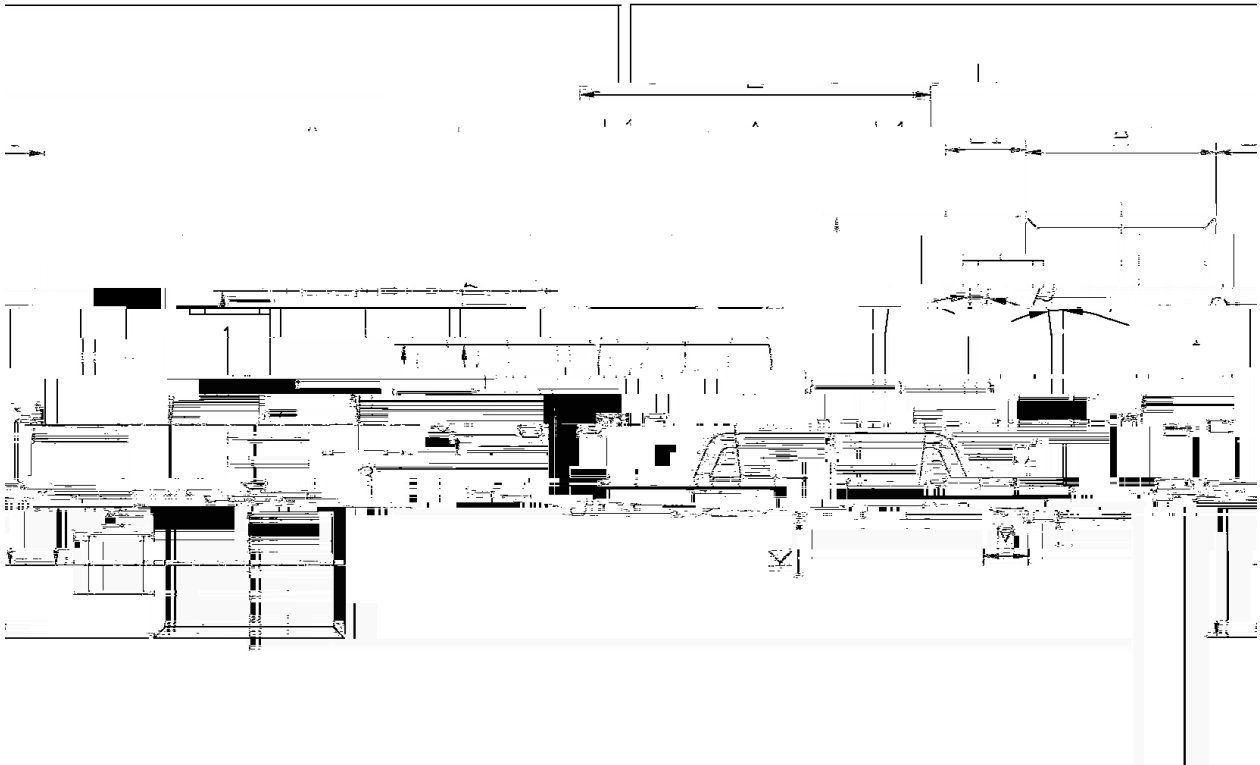




外形尺寸图

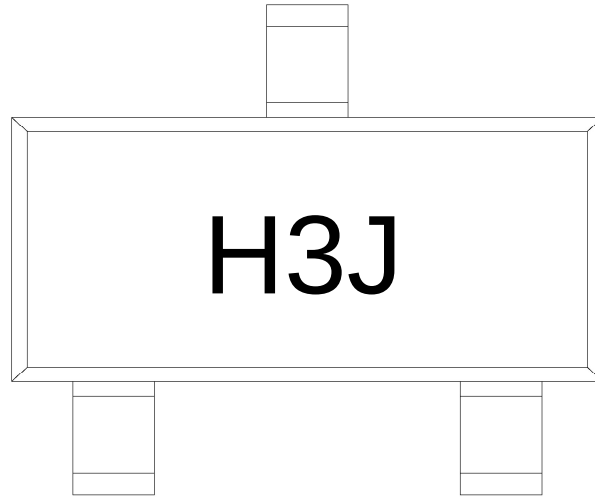
FSBT-22

单位: mm





印章说明



H

3J

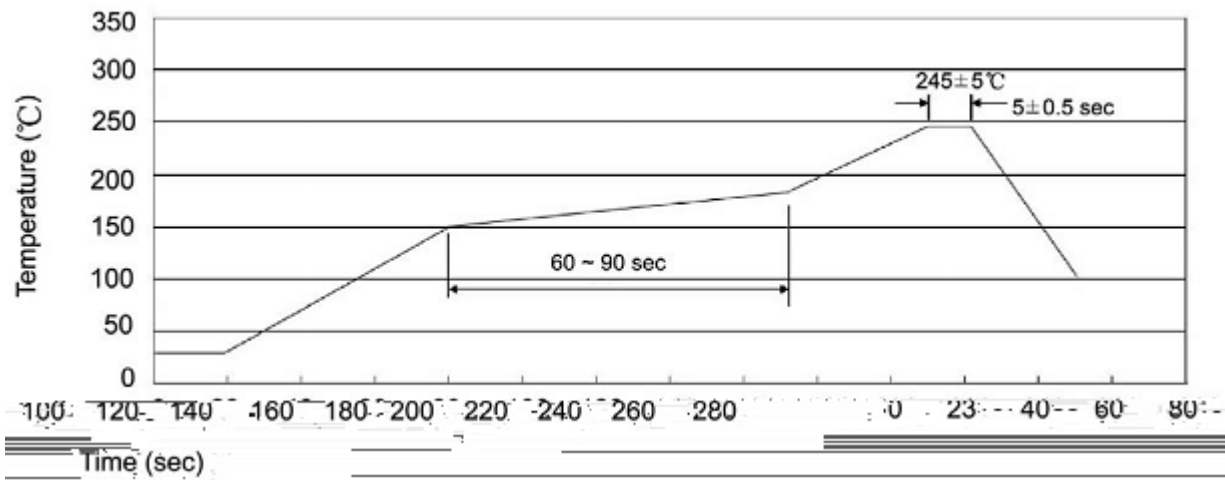
Note:

H: Company Code

3J: Product Type Code



回流焊温度曲线图 无铅 . Temperature Profile for IR Reflow Soldering(Pb-Free)



Note:

- | | | | | | |
|---|-------|-----|-----------|---|--------------------------------------|
| 1 | 25 | 150 | 60 | 90sec; | 1.Preheating:25~150 , Time:60~90sec. |
| 2 | 245±5 | | 5±0.5sec; | 2.Peak Temp.:245±5 , Duration:5±0.5sec. | |
| 3 | | 2 | 10 | /sec. | 3. Cooling Speed: se ° |